Revealing polarons with high pressure on low electron-doped manganites

G. Garbarino and C. Acha<sup>y</sup>
Laboratorio de Bajas Temperaturas, Depto. de F sica,
FCEyN, Universidad de Buenos Aires, Pabellon I,
Ciudad Universitaria, 1428 Buenos Aires, Argentina

D. Vega, G. Leyva, and G. Polla Departamento de F sica, Comision Nacional de Energ a Atomica, Gral Paz 1499, 1650 San Mart n, Buenos Aires, Argentina

C.Martin, A.Maignan, and B.Raveau Laboratoire CRISMAT, UMR 6508, ISMRA, 14050 Caen Cedex, France (Dated: January 10, 2022)

P ressure sensitivity (up to 1 GPa) of the electrical resistivity and of the ac susceptibility was measured for low electron doping levels of Ca<sub>1</sub> x Y x M nO<sub>3</sub> (CYMO) and of Ca<sub>1</sub> x Sm x M nO<sub>3</sub> (CSMO) ceram ic samples (0.05 x 0.15). A very weak pressure dependence of the Curie temperature (T<sub>c</sub>) was observed for both systems ( 6 K GPa<sup>1</sup>), when compared to the hole-doped manganites of the same T<sub>c</sub> ( 20 K GPa<sup>1</sup>). Our results can be interpreted within a modied Double Exchange scenario, where pressure alters the reduction of the bandwidth produced by the electron-phonon interaction associated with small Frohlich polarons in the weak to intermediate coupling regime.

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### I. INTRODUCTION

The study of high pressure e ects on the magnetic transitions and the electrical transport properties of manganite compounds can provide useful information about the relevant mechanism in magnetic ordering and its relation to transport properties. Indeed, this was the case for the pressure dependence of the Curie temperature ( $T_{\rm C}(P)$ ), mostly studied, up to now, in the hole-doped part of the phase diagram of these compounds.

It was experimentally show n<sup>1,2</sup> that the pressure coecient (dln ( $T_c$ )/dP) as a function of  $T_c$  follows a sort of universal curve, independent of the mean A ionic radius  $R_A$  (1.124 A <  $R_A$  < 1.147 A) for the  $A_{0:67}B_{0:33}M$  nO  $_3$  compounds (A = Pr, Sm, Nd, Y, La; B = Ca, Sr), or the doping level x (0.2 x 0.4) for La  $_x$  Sr $_x$ M nO  $_3$  and Nd<sub>1 x</sub> Sr $_x$ M nO  $_3$ .

It has also been show  $n^1$  that a qualitative understanding of this curve can be obtained in terms of the double exchange (DE) mode $1^{3}$ , Within this model, pressure increases the transfer integral of the eq electron, which is hopping from  $M n^{3+}$  to  $M n^{4+}$ . This results in a broadening of the bandwidth  $(W_0)$  which yields an increase of  $T_c$ . This can be understood by considering the pressure dependence of two geom etric or steric factors, both of which controlW  $_{0}$  : The M n-O distance (d\_M  $_{\rm n}$  O ) and the bending angle ( ) of the M n-O-M n bond. However, calculations based on a simple model related to pressure variations of the steric factors do not give a good quantitative agreem ent with the experim ental data. A better quantitative prediction can be obtained by considering the polaronicm odi cations of W 0 due to the Jahn-Teller (JT) cooperative e ect, which was clearly established for some of the manganite members. It has been shown that a pos-

itive contribution to the pressure dependence of Tc arises from the negative pressure derivative of the isotope exponent, = 1=2 E<sub>JT</sub> = h!, where is a positive constant 1),  $E_{JT}$  is the Jahn-Teller energy and ! an appropriate optical frequency. Even though, the experim ental results could not be suitably thed by this model, as for example, in the case of the studies of the oxygen-isotope e ects under pressure in the La<sub>0:65</sub>C a<sub>0:35</sub>M nO<sub>3</sub> sam ples<sup>6</sup>, the dlnT c/dP value observed for the 180 sample (23%) is higher than the one predicted by this model (6%). It was show n<sup>7</sup> that this controversy can be solved considering the polaron theory in the intermediate electron-phonon coupling region ( 1) and in the adiabatic approxim ation<sup>8</sup>, which also gives an adequate description of the electrical conductivity for tem peratures above  $T_c$ .

The study of electron-doped m anganites can shed light on the issue whether polarons are relevant or not to the  $T_{\rm c}$  (P ) dependence in m anganites. As the low  $e_{\rm g}$  level occupancy of the M  $n^{4+}$  ions no longer favors the JT distortion, JT polaronic e ects are not expected to contribute to transport properties or to magnetic ordering in the same way they are suspected to participate in the hole-doped part of the phase diagram . Then, a small  $T_{\rm c}$  (P) dependence for the electron-doped manganites would revealthe important role played by JT polarons in the hole-doped samples and may also indicate, on the other hand, an active role of other type of charge carriers, like lattice ormagnetic polarons, associated with the electron-doped manganites in other studies  $^{9,10}$ .

For low doping levels (0.05 x 0.15),  $Ca_{1 \times} Y_x M nO_3$  (CYMO) and  $Ca_{1 \times} Sm_x M nO_3$  (CSMO) compounds are typical electron-doped manganites. For this doping regime a competition between antiferromagnetic (AF) superexchange and ferromagnetic (FM) dou-

ble exchange (DE) interactions has been revealed by dom agnetization and electrical transport measurements as a function of temperature and magnetic eld for the CYMO system  $^{11,12,13}$ . Neutron di raction studies  $^{14,15}$  for CSMO (x=0.10 and x=0.15) showed that, besides the FM phase, a Pnm a structure associated with a G-type AF is also present in the paramagnetic state. At 10 K, the sample with x=0.10 exhibit a G-type AF phase, but for x=0.15 the C type magnetic order (characterized by a P  $2_1/\mathrm{m}$  space group) dominates, coexisting with smaller G AF clusters.

In this paper we study the high pressure e ects on the resistivity and ac susceptibility as a function of tem perature of the low electron-doped CYMO and CSMO manganese perovskites. A lithough an expected weak pressure dependence of  $T_{\rm c}\left(P\right)$  was observed, a quantitative agreement could not be obtained by solely considering the pressure sensitivity of the steric factors within a DE scenario. Our results indicate that the characteristic hopping conduction and the value of the pressure coe cient d (hT\_c)/dP can be ascribed to the polaronic nature of carriers, which can be associated with small Frohlich polarons in a weak to intermediate coupling regime.

### II. EXPERIMENTAL

Single phase and well oxygenated C  $a_{1} \times Y_x M nO_3$  (CYMO; x=0.06; 0.07; 0.08; 0.10) and C  $a_{1} \times Sm_x M nO_3$  (CSMO; x=0.10; 0.15) ceram ic samples were prepared by solid state reaction. This samples had been previously studied and the details of their synthesis and characterization have been published elsewhere  $^{11,12,14,15,16,17,18,19,20}$ .

Resistivity ( (T)) and ac susceptibility (  $_{\rm ac}$  (T)) were measured as a function of temperature ( 4 K  $_{\rm T}$  300 K) applying high hydrostatic pressures up to 1 GPa. A self-clamping cell was used with a 50-50 m ixture of kerosene and transformer oil as the pressure transmitting medium . (T) was measured following a standard 4 term inal DC technique, while  $_{\rm ac}$  (T) was evaluated using an applied ac magnetic eld of 10 e at an excitation frequency of ' 1 kHz.

# III. RESULTS AND DISCUSSION

Resistivity as a function of temperature for dierent pressures is displayed in Fig. 1 for CYMO (x=0.08;0.10) and CSMO (x=0.10). A metallic conductivity at room temperature followed by a semiconducting-like behavior when decreasing temperature can be observed for both compounds. The low temperature resistivity shows in all cases a divergence characteristic of an insulator behavior.

The ferrom agnetic transition temperature  $(T_c)$  can be associated with an in exion or a small drop in the resistivity, depending on doping level, as well as with a peak

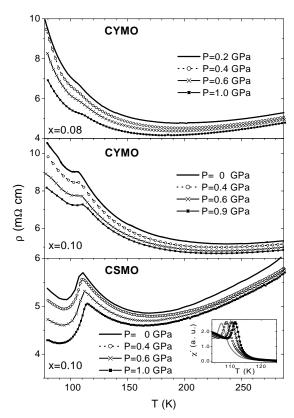


FIG. 1: Pressure dependence of the resistivity as a function of tem perature of CYMO for x=0.08; 0.10 and of CSMO for x=0.10. The inset shows the peak observed in the real part of the ac susceptibility (T) for the ferrom agnetic transition of this latter sample. Similar transport and magnetic results are obtained for x=0.06 (CYMO) and x=0.15 (CSMO), not shown here for clarity.

in the ac susceptibility, as can be noticed in the inset of Fig. 1. The low temperature part of  $_{\rm ac}$  (T), which can be associated with the behavior of a cluster glass  $^{17}$ , will not be considered here, as we want to focus our study on the appearance of the ferrom agnetic ordering and its sensitivity to the applied pressure.

P ressure decreases resistivity and enhances the resistivity drop at  $T_{\rm c}$ .  $T_{\rm c}$  was determined using the peak of the logarithm ic temperature derivative of (T) and  $_{\rm ac}$ (T) curves, as illustrated in the inset of Fig.2. The obtained pressure sensitivity of  $T_{\rm c}$ , depicted in Fig.2 and in Fig.3, depends on the technique used to characterize the sample. A non-monotonic dependence is observed for the resistivity data:  $T_{\rm c}$  remains nearly constant for low pressures and then softly increases for higher pressures with a slope  $5-7~{\rm K~G\,Pa^{\,1}}$ . On the other hand, susceptibility data shows essentially a linear increase of  $T_{\rm c}$  with pressure with a sin ilar slope.

These di erences can be associated with the fact that (T) is related not only to the magnetic ordering of the sample but also to a percolation problem. The percolation scenario can be generated by the coexistence of dif-

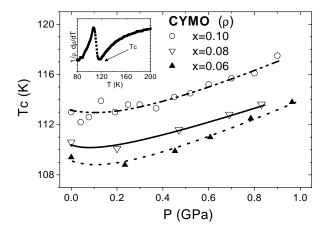


FIG. 2: P ressure dependence of the ferrom agnetic transition tem perature  $T_{\text{c}}$  of C Y M O . In the inset, the criteria to de ne  $T_{\text{c}}$  from the  $\,$  (T) m easurem ents is presented.

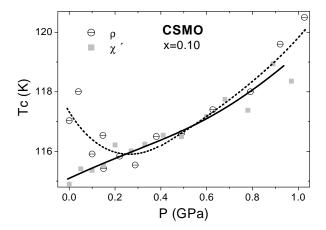


FIG .3: Com parison of the pressure dependence of the ferromagnetic transition temperature  $T_{\text{c}}$  of CSM O obtained using the temperature logarithm ic derivative of (T) and (T).

ferent conducting phases and by their pressure-dependent relative distribution. This was already demonstrated by neutron di raction studies of these sam ples, as the coexistence of FM clusters in an AFM matrix. Although the pressure dependence of  $T_c$  obtained from  $_{ac}(T)$  should then be more reliable, both methods produce similar results if only the high pressure portion of the curves is analyzed. Considering this criterion, the pressure coecient,  $d\ln T_c/dP$ , can be determined from the  $T_c(P)$  curves obtained using both techniques. As shown in Fig.4, this coecient is for all the samples (0.05 0.01) GPa  $^1$ , which is far from the usual values  $^2$  (universal curve) obtained for hole-doped manganites in this  $T_c$  range (0.20 GPa  $^1$ ).

In a DE scenario the FM transition temperature ( $\Gamma_c$ ) is proportional to the bare bandwidth (W  $_0$ ), which depends on the steric param eters, d<sub>M n O</sub> and (P)  $^{21}$ . It can be

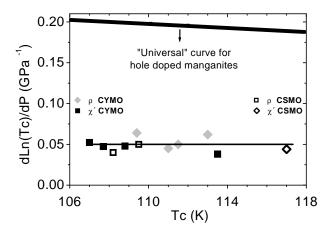


FIG. 4: Dependence of the pressure coe cient dlnT  $_{\text{c}}$ /dP as a function of T $_{\text{c}}$  for the CYMO and CSMO electron-doped manganites (determined from (T) or (T) measurements). The universal curve is a guide to represent data of hole-doped manganites as described in the text.

shown that the pressure coe cient can then be estimated as  $^{1}$ :

$$\frac{\text{dlnT}_c}{\text{dP}} = 3.5 \, (\mathbf{M}_{n \, 0}) \, 2 \, \text{tan} \, () \, () \, (1)$$

where ( $d_{M\ n\ 0}$ ) and () are the bond length and bond angle compressibilities, respectively. Using equation 1 and the values already measured for other manganese perovskites<sup>22</sup>, we can evaluate a contribution, at the most, of 0.01 GPa  $^1$  to the pressure coe cient produced by the variation of these steric factors. This small value, compared with our experimental results in Fig.4, reveals the existence of other contributions, which may be based on the polaronic nature of electrical carriers. Though JT collective polarons are not expected in this samples, local lattice distortions or magnetic interactions may play an important role, which may be noticed in the transport properties.

In this sense, the temperature dependence of the resistivity of these samples seems to be a characteristic behavior of the electron-doped manganites, as previously reported in the literature  $^{11,12,17,23}$ . The observed dependencies (see Fig.1) are typical of degenerate semiconductors, where a metallic-like conductivity can be observed at room temperature, while a thermally activated hopping of carriers dominates the conduction mechanism at low temperatures. The possibility of having a Variable Range Hopping conduction  $^{24}$  was also considered, but an examination of the data rules out this possibility.

We analyze our data considering that the electrical transport at interm ediate tem peratures is electively related to the hopping of polarons. As it was shown for the hole-doped manganites, an adequate description should be performed in the adiabatic limit, which must be maintained for the electron-doped samples, as similar charac-

teristic times are expected to be involved. In this case, the resistivity can be expressed as:

$$(T) = {}_{0} \exp{(\frac{E_a}{k_B T})}$$
 (2)

w ith an activation energy, E  $_{\rm a}$ , that can be approxim ated by

$$E_a = \frac{1}{2}E_p \quad J' \frac{1}{2}E_p \quad \frac{W_0}{2z}$$
 (3)

where E  $_{\rm p}$  is the binding energy of the polaron, J the electron transfer integral between nearest neighbor sites, W  $_{\rm 0}$  is the bare bandwidth, z the lattice coordination number and  $k_{\rm B}$  the Boltzm ann constant.

In the case that carriers could be associated with a polaronic nature, the bare bandwidth W  $_0$  should be narrowed as a consequence of the electron-phonon interaction, producing an elective smaller W . W and W  $_0$  can be related by the following expression:

$$W = W_0 F \quad (E_p; ;!_0)$$
 (4)

where E  $_{\rm p}$  is the polaron binding energy,  $=\frac{E_{\rm p}}{W_{\rm 0}=2}$  the dimensionless electron-phonon coupling constant and  $!_{\rm 0}$  a characteristic optical phonon frequency. The F are dierent functions, de ned according to the value of , which determines the coupling regime  $^{8,25}$ . For example, in the strong coupling regime ( 1), F '  $\exp{(E_{\rm p}=h!_{\rm 0})}$ , but this function is not valid anymore for the intermediate coupling regime as pointed out by A lexandrov and M ott<sup>25</sup>.

From Eqs. (3) and (4) we obtain that

$$E_a = \frac{1}{2}E_p \quad \frac{CT_c}{F} \tag{5}$$

Following the description of Lorenz et all, we have plotted in Fig. 5 the activation energy  $E_a$  as a function of  $T_{\rm c}$  obtained for di event pressures for the CYMO and CSMO with di event doping levels. Except for the lowest  $T_{\rm c}$  values, where, as already mentioned, their determination is in uenced by the percolation problem, an almost linear dependence is obtained. This indicates that  $E_{\rm p}$  and  $F_{\rm c}$  are essentially constants within our experimental pressure range, independently of the pressure variation of all relevant parameters.

A linear t of the curves of Fig. 5 yields an estimation of  $E_p$  ′ 120-180 m eV. The increasing value with increasing doping may point to a tendency to localization, produced by the size-m ism atch of replacing C a with small ions like Y or Sm. In this case, considering that  $W_0$  ′ 1 eV, the coupling constant can be estimated as

' 0:3, which determ ines a weak to interm ediate coupling regime. This value is over 4 times smaller than the one typically obtained for the hole-doped manganites<sup>26</sup>.

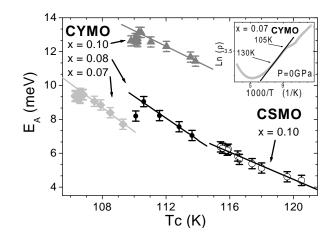


FIG.5: A ctivation energy E  $_{\rm a}$  as a function of T  $_{\rm c}$  for CYMO and CSMO with dierent doping level. The inset shows an example of the Ln() vs. 1/T curves from which the E  $_{\rm a}$  values were extracted.

Based on the fact that the electron-doped manganites are very poor conductors, particularly for the low doping range here analyzed, we can assume the fram ework introduced for doped manganites and other oxides by Alexandrov et al<sup>27,28</sup>, where smallor lattice polarons with a long range Frohlich interaction are the quasiparticles involved in the electrical transport properties of these materials. Thus, for these small Frohlich polarons we can consider the Frohlich electron-phonon coupling constant

$$= \frac{e^2}{K_p} \left(\frac{m}{2h^3!_0}\right)^{1=2} \left(\frac{1}{4_0}\right)$$
 (6)

where K  $_{\rm p}^{-1}$  =  $_{\rm 1}^{-1}$  +  $_{\rm s}^{-1}$  is the electric dielectric constant and  $_{\rm S}$  and  $_{\rm 1}$  the static and the high frequency dielectric constants, respectively, e the electron charge, m the electron band m ass and  $_{\rm 0}$  the vacuum perm it vity.

Following Feynm an's approach for the weak to intermediate coupling regim  $e^{29,30}$ , we can express E  $_{\rm p}$  and the polaronic e ective mass, mas a function of :

$$E_p = (+0.0123^{-2})h!_0$$
 (7)

$$\frac{m}{m} = 1 + \frac{1}{6} + 0.025^{-2}$$
 (8)

Considering a typical phonon frequency  $(!_0)$  of the order of 400 to 500 cm  $^1$ , estimated from Raman spectroscopy studies of CaM nO $_3$ <sup>31</sup>, and taking a mean value of E $_p$  = 0.15 eV from our data, we obtain from Eqs. 6, 7 and 8 that K $_p$  = 11 1, = 1.5 0.1 and m =m ' 1.3, respectively. The last two values are in accordance with the assumption of being in the intermediate coupling regime  $^{30}$  (1 6; m/m < 3). Also,

assum ing that the electron band mass is similar to the electron m ass (m me), the polaron localization radius  $R_p = (h/m!_0)^{1=2}$ 8 A 2 d<sub>M n O M n</sub> determines a polaron size in the lim it of being considered small. W hile the radius of the lattice distortion produced by the long range Frohlich interaction can be estimated<sup>24</sup> 30 A. These values are in as  $R_d = 5hK_p = (m e^2)$ good accordance with the assumption of an electrical transport mediated by small Frohlich polarons, i.e. a small size for the electron localization and a large size for the lattice distortion. To our know ledge, there is at the time no experimental determination of 1 for any electron-doped m anganite, though a very high lowfrequency dielectric constant up to 10° was measured at room temperature in  $Ca_{1\ x} La_{x}M$  nO  $_{3}$  (x  $3 \text{ w as estim ated for LaM nO}_3^{27}$ , a higher value for the electron-doped  $C = M \times NO_3$  can be expected, as a consequence derived from Eq. 6 and its lower coupling constant, when compared with the former manganite.

At this point, we can try to make a rough approxim ation to determ ine what is the contribution to the pressure coe cient produced by the dependence of the bandwidth on the mass enhancement, related to the polaronic nature of carriers. To do so, we can consider the approximation of slow polarons (k q, where k and q, are the electron and the phonon momenta, respectively)  $^{25}$  where the bandwidth W is essentially modiled as

$$W = \frac{W_0}{m = m}$$
 (9)

U sing Eqs. 8 and 9, the pressure coe cient can then be expressed as

$$\frac{\text{dlnTc}}{\text{dP}}, \frac{\text{dlnW}_0}{\text{dP}} \frac{\text{m}}{\text{m}} \frac{\text{d(m = m)} d}{\text{d}} \frac{\text{d!}}{\text{d!}}$$
(10)

From Eqs.6 and 7 and assuming that d!=dP = !0 (with 0.01 GPa¹) from reference 33, we can evaluate the second term of Eq. 10, which gives a positive contribution of 0.02 GPa¹, which is in good agreement with the results presented in Fig.4. Therefore, these results reveal the necessity of considering an additional contribution to the pressure coe cient besides the one which arises out of the steric factors. The additional contribution can be consistently related to the pressure sensitivity of intermediate-coupling Frohlich polaronic elects on the bandwidth.

## IV. CONCLUSIONS

We have studied the pressure sensitivity of the resistivity and of the ferrom agnetic ordering of electron-doped manganese perovskites (CYMO and CSMO) in the low doping regime. The obtained values of dln  $T_{\rm c}/{\rm dP}$  are considerably smaller than the ones measured for hole-doped manganites in the same  $T_{\rm c}$  range. Within a DE scenario this values can not be explained as a consequence of the pressure variation of steric factors. A better quantitative agreement can be obtained if a scenario of small intermediate-coupled Frohlich polarons is considered.

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scholarship of CONICET of Argentina

y fellow of CONICET of Argentina; Electronic address: acha@ dfubaar

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